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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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High Reliability NPN Silicon Phototransistor



OP804, OP805 (TX, TXV)

Features:

- TO-18 hermetically sealed package
- · Lensed for high sensitivity
- Narrow acceptance angle
- Processed after MIL-PRF-19500
- Mechanically and spectrally matched to high reliability IREDs in the



Description:

Each device in this series consists of a high reliability NPN silicon phototransistor mounted in a hermetically sealed TO-18 package, which offers high power dissipation and superior hostile environment operation. Device lensing creates a 12° angle when measured from the optical axis to the half power point.

These devices can be matched with a solid state infrared source (such as the high resolution OP235 and OP236 series of IREDs), or can be used to sense infrared content in a visible light source (such as a tungsten bulb or sunlight) for automatic brightness control.

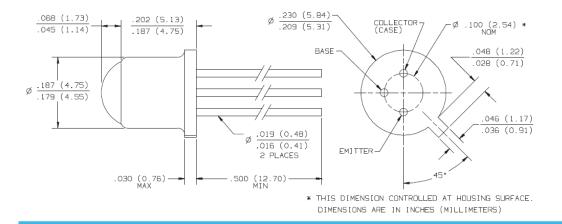
TX and TXV devices are processed to MIL-PRF-19500.

Please refer to Application Bulletins 208 and 210 for additional design information and reliability (degradation) data.

Applications:

- Space-limited applications
- Hostile environment applications

Part Number	Sensor	Light Current I _{C(ON)} (mA) Min / Max	V _{CE} Typ/Max	Input Power E _E (mW/cm ²)	Viewing Angle	Lead Length
OP804TX		7.00 / 22.00				
OP804TXV	Transistor	7.00 / 22.00	5	F 0	25°	0.50"
OP805TX	Transistor	15 00 / NA) 3	5.0	25	0.50
OP805TXV		15.00 / NA				



General Note

High Reliability NPN Silicon Phototransistor



OP804, OP805 (TX, TXV)

Absolute Maximum Ratings (T_A=25°C unless otherwise noted)

Storage Temperature Range	-65° C to +150° C
Operating Temperature Range	-55° C to +125° C
Collector-Base Voltage	30 V
Collector-Emitter Voltage	30 V
Emitter-Base Voltage	5 V
Emitter-Collector Voltage (applies to all OP800 and OP830 devices)	5 V
Lead Soldering Temperature [1/16 inch (1.6mm) fro case for 5 seconds with soldering iron] (1)	260° C
Power Dissipation ⁽²⁾	250 mW

Electrical Characteristics (T_A = 25°C unless otherwise noted)

Input Diode

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SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS	
I _{C (ON)}	On-State Collector Current OP804 (TX, TXV OP805 (TX, TXV)	7.0 15.0		8	mA	V _{CE} = 5.0V, E _e = 20 mW/cm ²⁽³⁾	
I _{CEO} Collector	Collector Emitter Dork Current			100	nA	V _{CE} = 10.0 V, E _e = 0	
	Collector-Emitter Dark Current			100	μΑ	V _{CE} = 30.0 V, E _e = 0 T _A = 100° C	
V _{(BR)CEO}	Collector-Base Breakdown Voltage	30			V	I _C = 100 μA, I _B = 0, E _e = 0	
V _{(BR)ECO}	Emitter-Collector Breakdown Voltage	7.0			V	I _C = 100 μA, E _e = 0	
V _{CE(SAT)}	Collector-Emitter Saturation Voltage			0.40	V	$I_C = 0.4 \text{ mA}, E_e = 20 \text{ mW/cm}^{(2)(3)}$	
t _f	Rise Time OP804 (TX, TXV) OP805 (TX, TXV)			10.0 15.0		V = 20 V L = 1.00 mA BL 100 C	
t _r	Fall Time OP804 (TX, TXV) OP805 (TX, TXV)			10.0 15.0	μs	$V_{cc} = 30 \text{ V}, I_c = 1.00 \text{ mA}, RL = 100 \Omega$	

Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- (2) Derate linearly 2.5 mW/° C above 25° C.
- (3) Light source is an unfiltered rungsten lamp operated at a temperature of 2870 K

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